NATIONAL INSTITUTE OF TECHNOLOGY, TIRUCHIRAPPALLI

DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING

This course outline template acts as a guide for writing your course outline. As every course is different, please feel free to amend the template/ format to suit your requirements.

COURSE OUTLINE	TEMPLATE		
Course Title	SEMICONDUCTOR PHYS	SICS AND DE	EVICES
Course Code	ECPC13	No. of Credits	3
Department	E.C.E	Faculty	R.K.KAVITHA
Pre-requisites Course Code	None	Ina Seemal	
Course Coordinator(s) (if, applicable)	R.K.Kavitha		
E-mail	rkkavitha@nitt.edu	Telephone No.	0431-2503322
Course Type	Core course	Elective	course
COURSE OVERVIE	W		
Properties. COURSE OBJECTIVE To make the s		nentals of ele	
COURSE OUTCOM	ES (CO)	Vicamin's	milium in the second
Course Outcomes			Aligned Programme Outcomes (PO)
Students are able to CO1: apply the knowle physics and understan CO2: analyze the chardiode, transistor etc.,	dge of basic semiconductor mate d fabrication processes. acteristics of various electronic de yze the various circuit configurations	evices like	,2,3,4
CO4: illustrate the qua Devices.	litative knowledge of Power electrons of the latest technological changes		,10,12

S.No. Day		Topic	Mode of Delivery	
1. 1		Course Introduction	Lecture / Tutorial	
2.	2	C & T / PPT		
3.	3	or any suitable mode		
4.	4 Conductivity Of Semiconductor, Equilibrium Carrier concentration			
5.	5	Density of states and Fermi level, Carrier transport – Drift and Diffusion		
6.	6	Continuity Equation and Hall Effect		
7.	7	Basic Crystal Structure, Crystal growth techniques for Si and GaAs (Czocharalski Method)		
8.	8	Float Zone method, Bridgman Technique		
9.	9	Epitaxial Growth Technique		
10.	0. 10 Lithography Etching Methods			
11.		UNIT II		
12.	11	PN Junction Diodes Introduction, Pn Junction as a rectifier	Lecture / Tutorial	
13.	12	Energy Band Structure, Current Components	C & T / PPT or any suitable mode	
14.	13	Volt –Ampere Characteristics		
15.	Diode Resistance, transition & diffusion Capacitance			
16.		Problem Solving Skill test		

17.	15	Different types of Diodes (Zener , Schottky, photo diode,etc)		
18.	16	Limiting and Clamping Circuits, Breakdown Mechanism in Diodes		
19.		Assessment –I Cycle Test 1	D REE IN	
20.		UNIT III		
21.	17 BJT Introduction, Modes of operation		Lecture / Tutorial	
22.	18 BJT Current components		C & T / PPT	
23.	19 BJT models		or any suitable mode	
24.	20 BJT as a Switch, Breakdown mechanisms			
25.	21 Photo Devices			
		Mini-Project		
26.		UNIT IV		
27.	MOSFET Operations, Structure, Types		Lecture / Tutorial	
28.	23	V-I Characteristics	C & T / PPT	
29.	Second order effects, MOSFET as an amplifier and switch		or any suitable mode	
30.	25 Capacitance and equivalent model			
31.	26	CMOS structure, BiCMOS operations		
32.	27 Operation of CCDs			
33.		Assessment-II Cycle Test-II		
34.	Tall patt h	UNIT V		
35.	Power Devices Introduction, Operation and characteristics of thyristor family: SCR ,TRIAC, DIAC		Lecture / Seminars PPT or	
36.	30,31 Triggering power diodes, power transistors		any suitable mode	

37.	32,33	IGBTs, GTOs Fabrication and VI characteristics				
38.	34,35	Display Devices: LCD, Plasma & LED Display Panels				
39.	-111	End Semester				
COURS	E ASSESSME	NT MET	HODS			
S.No.	Mode of Asse	essment	Week/Date	Duration		% Weightage
1.	Cycle Test	- 1	3 rd week of August	1 hour	20	
2.	Cycle Test	-2	Last week of September	1 hour	20	
3.	Problem Solving Skill test		2 nd week of August and		10	
	Mini Projec	et	2 nd week of september		10	
4.	End Semest Exam	ter	4 th week October	3 hour	40	

ESSENTIAL READINGS: Textbooks, reference books Website addresses, journals, etc

Text Books

- 1. S.M.Sze, 'Semiconductors Devices, Physics and Technology, (2/e)", Wiley, 2002.
- 2. A.S.Sedra&K.C.Smith, "Microelectronic Circuits (6/e)", Oxford, 2010.
- 3. L.Macdonald&A.C.Lowe, "Display Systems", Wiley, 2003

Reference Books

- 1. J.Millman and C.C.Halkias, "Electronic devices and Circuits", McGraw Hill, 1976.
- 2. A.Bar-Lev, "Semiconductors and Electronic Devices, (3/e)", Prentice Hall, 1993.
- 3. B.G.Streetman, "S.K.Banerjee: Solid state Electronic devices, (6/e)", PHI, 2010.

COURSE EXIT SURVEY (mention the ways in which the feedback about the course is assessed and indicate the attainment also)

- 1. The students through class representative may give their feedback at any time which will be duly addressed.
- 2. Feedback from the students through MIS and class committee meetings.

COURSE POLICY (including plagiarism, academic honesty, attendance, etc.)

CORRESPONDENCE

1. All the students are advised to come to the class regularly. All the correspondence (schedule of classes/ schedule of assignment/ course material/ any other information regarding this

course) will be intimated in the class only.

ATTENDANCE

- 1. Attendance will be taken by the faculty. 100 % is a mandatory. However, the relaxation upto 20% will be given for leave on medical, and other essential requirements followed in the institute. Every student should maintain minimum 80% physical attendance in these contact hours along with assessment criteria to attend the end semester examination.
- 2. Any student who fails to maintain 80% and misses any lab experiment needs to appear for the compensation classes with regular evaluation process. Students attendance is compulsory for Quiz and end semester.
- 3.Students not having 80% minimum attendance with compensation at the end of the semester will have to REDO the course.

ASSESSMENT

- 1. Attending all the assessments are mandatory for every student.
- 2. Finally every student is expected to score minimum 1/3 rd of the top rank holder of the class (including all assessments) to pass the course. Otherwise student would be declared fail and 'F' grade will be awarded. Further he can take up only FORMATIVE ASSESSMENT.
- 3. Please refer to B.Tech., Regulations 2015 for the letter grades and corresponding grades.

Plagiarism, academic honesty: The students are expected to follow institute rules.

FOR SENATE'S CONSIDERATION

Course Faculty

CC-Chairperson

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